

isc Silicon NPN Darlington Power Transistor

2SD1230

**DESCRIPTION**

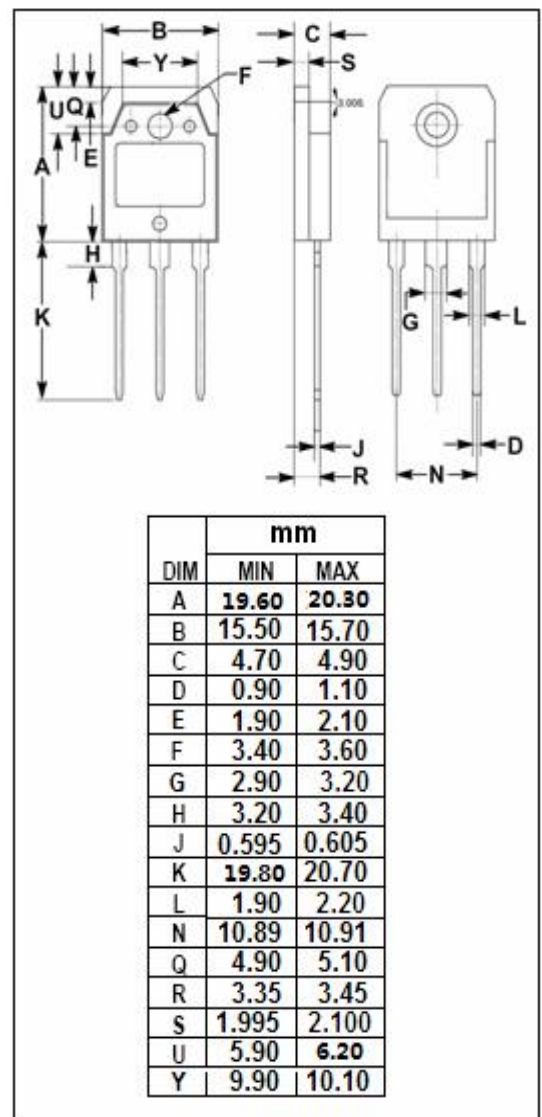
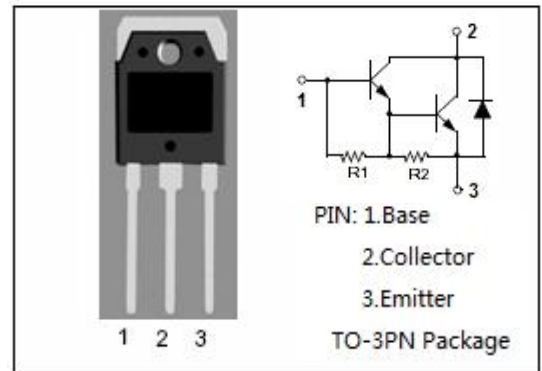
- High DC Current Gain  
:  $h_{FE} = 1500(\text{Min.}) @ I_C = 4A, V_{CE} = 3V$
- Collector-Emitter Breakdown Voltage-  
:  $V_{(BR)CEO} = 100V(\text{Min.})$
- Complement to Type 2SB913
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

**APPLICATIONS**

- Designed for motor drivers, printer hammer drivers, relay drivers, voltage regulator control applications.

**ABSOLUTE MAXIMUM RATINGS( $T_a = 25^\circ\text{C}$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	110	V
$V_{CEO}$	Collector-Emitter Voltage	100	V
$V_{EBO}$	Emitter-Base Voltage	6	V
$I_C$	Collector Current-Continuous	8	A
$I_{CM}$	Collector Current-Peak	12	A
$P_C$	Collector Power Dissipation @ $T_a = 25^\circ\text{C}$	2.5	W
	Collector Power Dissipation @ $T_c = 25^\circ\text{C}$	60	
$T_j$	Junction Temperature	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-55~150	$^\circ\text{C}$



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## ELECTRICAL CHARACTERISTICS

 $T_C=25^\circ\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C = 30\text{mA}; R_{BE} = \infty$	100			V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = 1\text{mA}; I_E = 0$	110			V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 4\text{A}, I_B = 8\text{mA}$			1.5	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 4\text{A}, I_B = 8\text{mA}$			2.0	V
$I_{CBO}$	Collector Cutoff current	$V_{CB} = 80\text{V}, I_E = 0$			0.1	mA
$I_{EBO}$	Emitter Cutoff Current	$V_{EB} = 5\text{V}; I_C = 0$			3.0	mA
$f_T$	Current-Gain—Bandwidth Product	$I_C = 4\text{A}; V_{CE} = 5\text{V}$		20		MHz
$h_{FE}$	DC Current Gain	$I_C = 4\text{A}; V_{CE} = 3\text{V}$	1500			
Switching Times						
$t_{on}$	Turn-On Time	$I_C = 4\text{A}, I_{B1} = I_{B2} = 8\text{mA};$ $R_L = 12.5\ \Omega; V_{CC} = 50\text{V}$		0.6		$\mu\text{s}$
$t_{stg}$	Storage Time			4.8		$\mu\text{s}$
$t_f$	Fall Time			1.6		$\mu\text{s}$

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